

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







TG-CJ-60-60-15-PF

Ceramic Heat Spreader





Features

Large contactarea Low weight High breakdown voltage Excellent heat spreader Custom shapespossible

Applications

LED/ NotebookPC/ M/B/ PowerTransistor/ PowerModule/CPU/ ChipIC

Main Component			AL ₂ O ₃
Physical Property	Density	g/cm³	3.66
	WaterAbsorption	%	0.002
	SinterTemperature	°C	1700
	Acidresistance	mg/cm³	≦ 0.2
	Alkali	mg/cm³	≦ 0.2
Mechanical Property	Mohs Hardness	HV	9
	BendStrength	Мра	≧610
	Compression Intensity	Мра	≧ 620
Thermal Property	Maximum working temperature	°C	1400
	Refractoriness	°C	≧ 1500
	thermal expansion coefficient	(1 x 10 ⁻⁶)mm/°C	7.8 ~ 8.3
	Thermal Shockresistance	T(°C)	200
	ThermalConductivity	W/m.k	40~51
Electrical Property	Resisting rate of Volume	Ω. °C	1016
	DC breakdown strength	KV/mm	15.2 ~ 16.7
	Insulation Breakdown Intensity	KV/mm	18
	Dielectric Constant (1MHz)	(E)	10
	Dielectric Dissipation	(tg o)	0.4*10 ⁻³